Future Synthesis and Annealing Program in CMPMSD



- Manufacturer: American Isostatic
 Presses, Inc
- Gas pressure to 100,000 psi, up to 20% Oxygen
- Installation: Chemistry, Site specifically configured for HIP
- Acceptance testing at BNL ongoing



Motivations for Hot Isostatic Press

- Oxygen Annealing for High Temperature Superconductors and for High Pressure Single Crystal Growth.
- Is High Tc primarily a 2D Phenomena occurring in CuO Planes?
- Can Tc be increased by Oxygen Annealing?
- Stored Energy Required ASME, Boiler and Pressure Vessel Code, Section VIII, Division 3



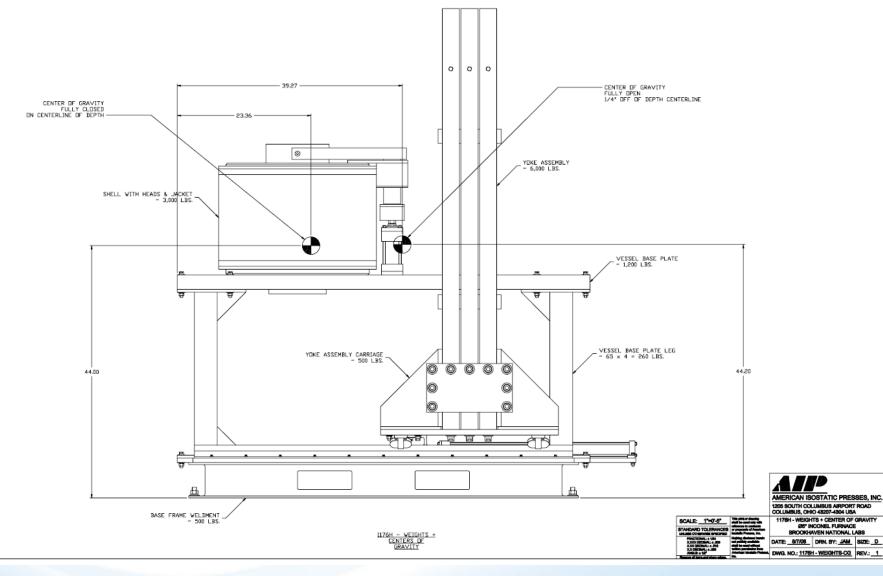
Overview of AIP Hot Isostatic Press

- Design Pressure
- Operating Pressure
- Hydrotest Pressure
- Furnace
- Oxygen Annealing
- Vessel Temp Range
- Inside Diameter
- Inside Length
- Internal Volume
- Vessel Weight
- Yoke Weight
- Stored Energy

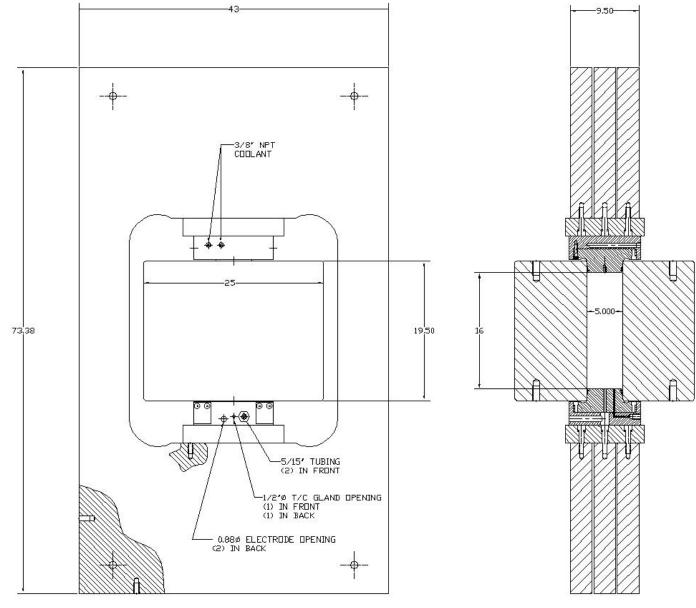
110,000 psi at 400° F 100,000 psi at 400° F 137,500-144,375 psi 1200° C to 20% Oxygen 40 - 400° F 4.998"/5.000" 16" Nominal 0.18 cubic feet 3000 lbs 6,000 lbs 2.5 Mega Joules ~ 1 stick of dynamite



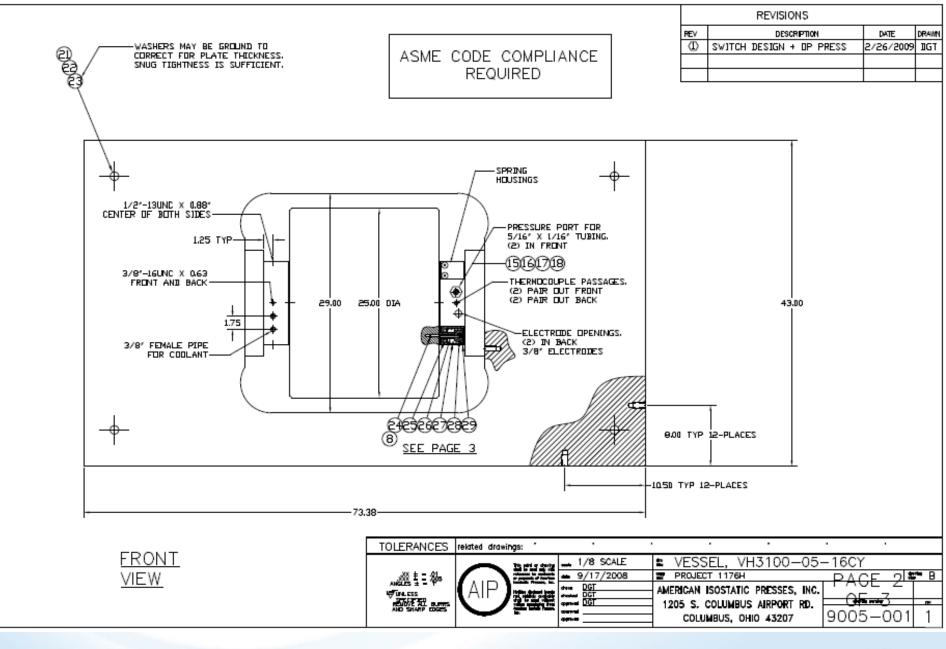
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1	ADDED CENTERS OF GRAVITY	9/16/2008	DGT	
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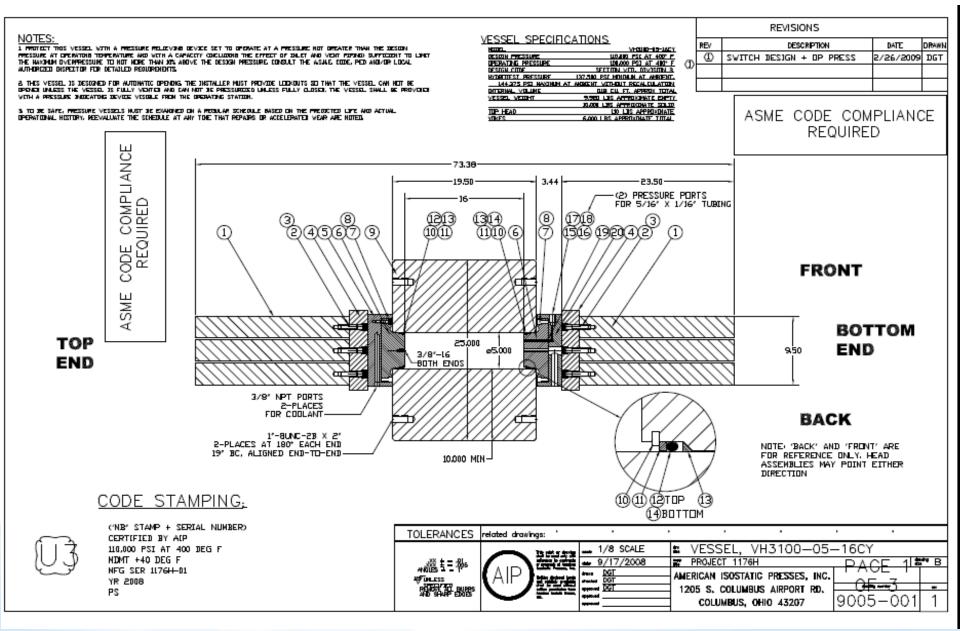










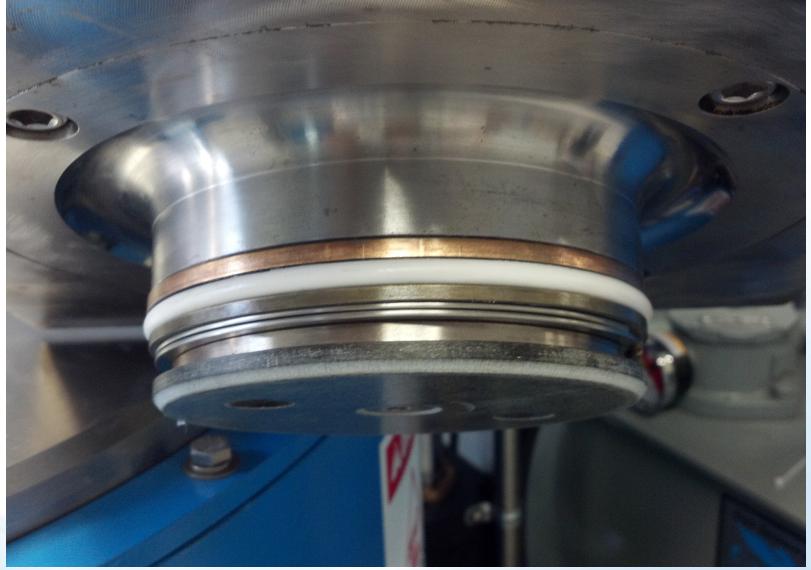






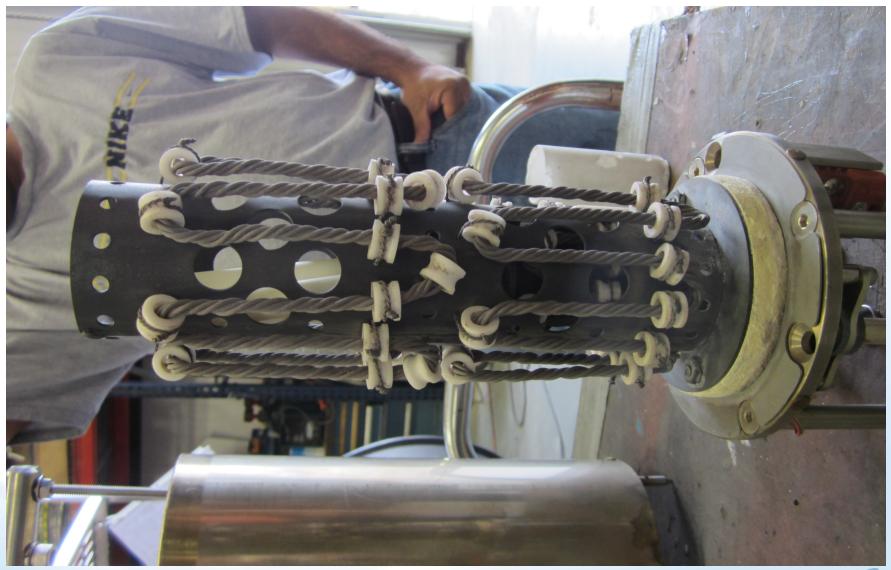


Top Platen











Bottom Platen, Electrodes, TC's



